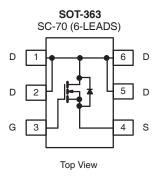


N-Channel 30 V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A) ^{a, e}	Q _g (Typ.)			
30	0.040 at V _{GS} = 10 V	5.5	4.7 nC			
	0.050 at V _{GS} = 4.5 V	5	4.7 110			



FEATURES

- DT-Trench Power MOSFET
- Low On-Resistance
- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC



APPLICATIONS

• DC/DC Converters, High Speed Switching

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	30	V	
Gate-Source Voltage		V _{GS}	± 20	v
	T _C = 25 °C		5.5 ^e	
Continuous Prain Current (T = 150 °C)	T _C = 70 °C	1 , [5 ^e	
Continuous Drain Current (T _J = 150 °C)	T _A = 25 °C	l _D –	4.5 ^{b, c}	
	T _A = 70 °C	1	4.0 ^{b, c}	A
Pulsed Drain Current (t = 300 µs)		I _{DM}	22	
Continuous Source-Drain Diode Current	T _C = 25 °C		2.0	
Continuous Source-Drain Diode Current	T _A = 25 °C	- I _S -	1 ^{b, c}	
	T _C = 25 °C		2.2	
Maximum Power Dissipation	T _C = 70 °C	P _D	1.4	w
Maximum Power Dissipation	T _A = 25 °C		1.1 ^{b, c}	
	T _A = 70 °C	1	0.6 ^{b, c}	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C
Soldering Recommendations (Peak Tempera		260		

THERMAL RESISTANCE RATINGS								
Parameter	Symbol	Typical	Maximum	Unit				
Maximum Junction-to-Ambient ^{b, d}	t ≤ 5 s	R _{thJA}	85	110	°C/W			
Maximum Junction-to-Foot (Drain)	Steady State	$R_{th,IF}$	45	55]			

Notes

- a. Based on T_C = 25 °C.
- b. Surface mounted on 1" x 1" FR4 board.
- c. t = 5 s
- d. Maximum under steady state conditions is 166 $^{\circ}\text{C/W}.$
- e. Package limited.

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V, } I_D = 250 \mu\text{A}$	30			V
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	I _D = 250 μA		30		mV/°C
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	1D = 230 μΑ		- 4.8		
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	1.2		2.5	V
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA
Zoro Coto Voltago Droin Current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V			1	μΑ
Zero Gate Voltage Drain Current		$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			10	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			Α
	В	$V_{GS} = 10 \text{ V}, I_D = 4.5 \text{ A}$		0.033	0.040	Ω
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_{D} = 4 \text{ A}$		0.037	0.050	
Forward Transconductance ^a				24		S
Dynamic ^b						
Input Capacitance	C _{iss}			429		
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		100		pF
Reverse Transfer Capacitance	C _{rss}			42		
Tabal Oaks Observe	Qg	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 5.5 \text{ A}$		8.2	13	nC
Total Gate Charge				4.7	7	
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 5.5 \text{ A}$		1.4		
Gate-Drain Charge	Q_{gd}			1.4		
Gate Resistance	R_{g}	f = 1 MHz	2.5	12.6	25.2	Ω
Turn-On Delay Time	t _{d(on)}			6	12	ns
Rise Time	t _r	$V_{DD} = 15 \text{ V}, R_{L} = 3.4 \Omega$		20	30	
Turn-Off Delay Time	t _{d(off)}	$I_D \approx 4.4 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 1 \Omega$		14	21	
Fall Time	t _f			10	20	
Turn-On Delay Time	t _{d(on)}			3	6	
Rise Time	t _r	V_{DD} = 15 V, R_L = 3.4 Ω		11	20	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 4.4 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$		20	30	
Fall Time	t _f			7	14	
Drain-Source Body Diode Characteristi	cs					
Continuous Source-Drain Diode Current	Is	T _C = 25 °C			2.0	А
Pulse Diode Forward Current	I _{SM}				22	
Body Diode Voltage	V _{SD}	$I_S = 4.4 \text{ A}, V_{GS} = 0 \text{ V}$		0.82	1.2	V
Body Diode Reverse Recovery Time	t _{rr}			13	20	ns
Body Diode Reverse Recovery Charge	Q _{rr}	L = 4.4.4 dl/dt = 100.4/vo T = 25.90		6	12	nC
Reverse Recovery Fall Time	t _a	$I_F = 4.4 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 ^{\circ}\text{C}$		8		
Reverse Recovery Rise Time	t _b			5		ns

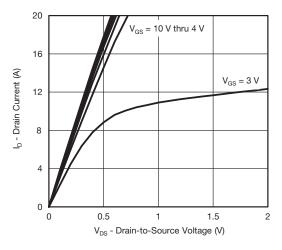
Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

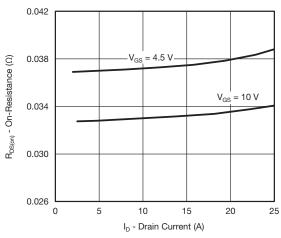
a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

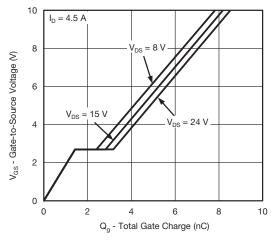
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



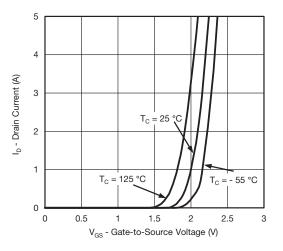
Output Characteristics



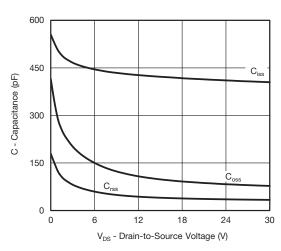
On-Resistance vs. Drain Current and Gate Voltage



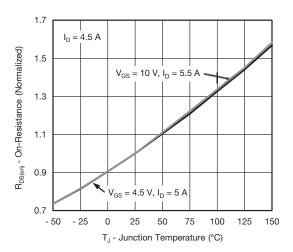
Gate Charge



Transfer Characteristics



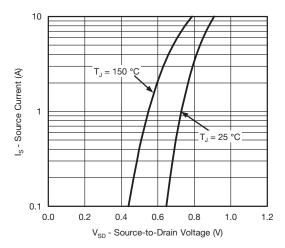
Capacitance



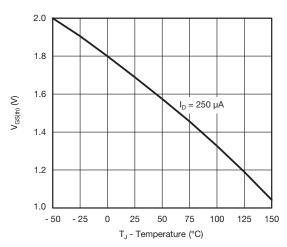
On-Resistance vs. Junction Temperature



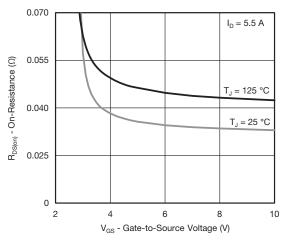
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



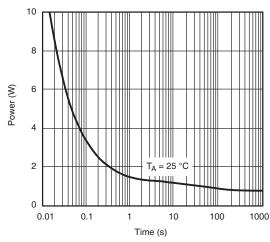
Source-Drain Diode Forward Voltage



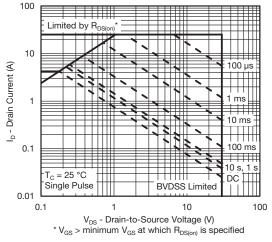
Threshold Voltage



On-Resistance vs. Gate-to-Source Voltage

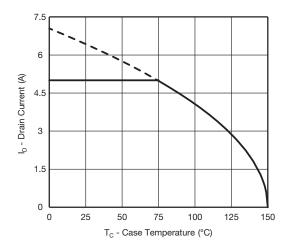


Single Pulse Power (Junction-to-Ambient)

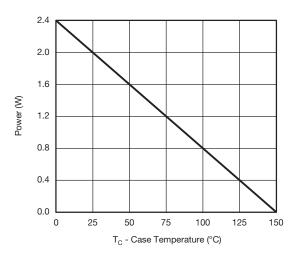


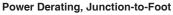
Safe Operating Area, Junction-to-Ambient

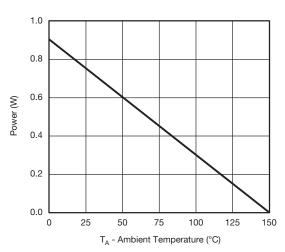
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating*





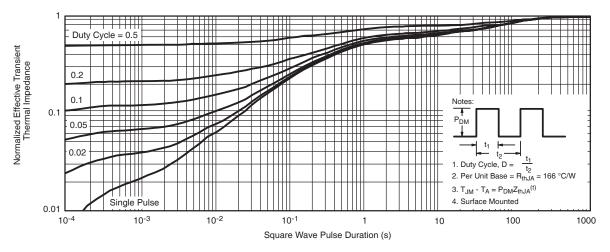


Power Derating, Junction-to-Ambient

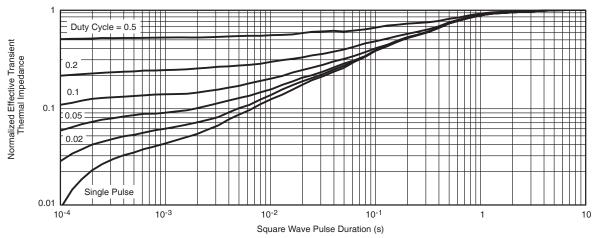
^{*} The power dissipation P_D is based on $T_{J(max.)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



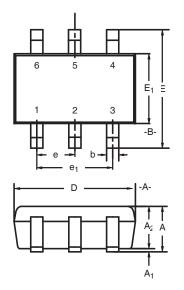
Normalized Thermal Transient Impedance, Junction-to-Ambient

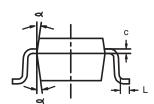


Normalized Thermal Transient Impedance, Junction-to-Foot



SC-70: 6-LEADS



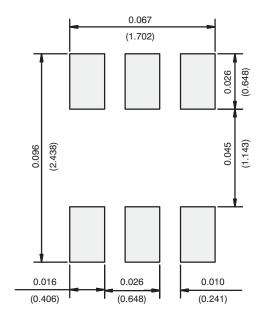


	MIL	LIMET	ERS	INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.90	-	1.10	0.035	-	0.043	
A ₁	-	_	0.10	-	-	0.004	
A ₂	0.80	-	1.00	0.031	-	0.039	
b	0.15	-	0.30	0.006	-	0.012	
С	0.10	-	0.25	0.004	-	0.010	
D	1.80	2.00	2.20	0.071	0.079	0.087	
Ε	1.80	2.10	2.40	0.071	0.083	0.094	
E ₁	1.15	1.25	1.35	0.045	0.049	0.053	
е	0.65BSC			0.026BSC			
e ₁	1.20	1.30	1.40	0.047	0.051	0.055	
L	0.10	0.20	0.30	0.004	0.008	0.012	
ø	7°Nom			7°Nom			
ECN: S-03946—Rev. B, 09-Jul-01							

DWG: 5550



RECOMMENDED MINIMUM PADS FOR SC-70: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)



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